

# HMC608LC4

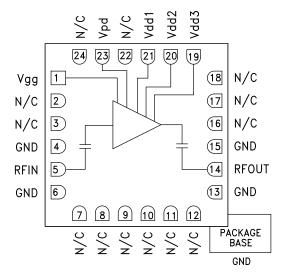
# GaAs pHEMT MEDIUM POWER AMPLIFIER, 9.5 - 11.5 GHz

# Typical Applications

The HMC608LC4 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- Military End-Use

### **Functional Diagram**



### Features

Output IP3: +33 dBm Saturated Power: +27.5 dBm @ 23% PAE Gain: 29.5 dB Supply: +5V @ 310 mA 50 Ohm Matched Input/Output RoHS Compliant 4x4 mm SMT Package

### **General Description**

The HMC608LC4 is a high dynamic range GaAs pHEMT MMIC Medium Power Amplifier housed in a leadless "Pb free" SMT package. The amplifier has two modes of operation: high gain mode (Vpd pin shorted to ground); and low gain mode (Vpd pin left open). The electrical specifications in the table below are shown for the amplifier operating in high gain mode. Operating from 9.5 to 11.5 GHz, the amplifier provides 29.5 dB of gain, +27.5 dBm of saturated power and 23% PAE from a +5V supply voltage. Noise figure is 6 dB while output IP3 is +33 dBm. The RF I/Os are DC blocked and matched to 50 Ohms for ease of use. The HMC608LC4 eliminates the need for wire bonding, allowing use of surface mount manufacturing techniques.

### Electrical Specifications, $T_{A} = +25^{\circ}$ C, Vdd1, 2, 3 = 5V, Idd = 310 mA<sup>[1]</sup>, Vpd = GND<sup>[2]</sup>

Parameter	Min.	Тур.	Max.	Units
Frequency Range		9.5 - 11.5		
Gain <sup>[3]</sup>	27	29.5		dB
Gain Variation Over Temperature		0.02	0.03	dB/ °C
Input Return Loss		13		dB
Output Return Loss		19		dB
Output Power for 1 dB Compression (P1dB)	23	27		dBm
Saturated Output Power (Psat)		27.5		dBm
Output Third Order Intercept (IP3)		33		dBm
Noise Figure		6.0		dB
Supply Current (Idd = Idd1 +Idd2 +Idd3)(Vdd = +5V, Vgg = -2.6V Typ.) [3]		310	350	mA

[[1] Adjust Vgg between -3 to 0V to achieve Idd = 310 mA typical.

[2] Vpd= ground for high gain mode, Vpd = open for low gain mode.

[3] In low gain mode, typical gain is 22 dB and typical current is 67 mA.

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# HMC608\* PRODUCT PAGE QUICK LINKS

Last Content Update: 11/29/2017

# COMPARABLE PARTS

View a parametric search of comparable parts.

# EVALUATION KITS

HMC608LC4 Evaluation Board

# **DOCUMENTATION**

### **Application Notes**

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers
- Broadband Biasing of Amplifiers General Application Note
- MMIC Amplifier Biasing Procedure Application Note
- Thermal Management for Surface Mount Components General Application Note

### Data Sheet

• HMC608LC4: GaAs pHEMT Medium Power Amplifier, 9.5 - 11.5 GHz Data Sheet

# TOOLS AND SIMULATIONS $\square$

HMC608 S-Parameter

# REFERENCE MATERIALS

### **Product Selection Guide**

• RF, Microwave, and Millimeter Wave IC Selection Guide 2017

### **Quality Documentation**

- Package/Assembly Qualification Test Report: LC4, LC4B (QTR: 2014-00380 REV: 01)
- Semiconductor Qualification Test Report: PHEMT-F (QTR: 2013-00269)

# DESIGN RESOURCES 🖵

- HMC608 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

## DISCUSSIONS

View all HMC608 EngineerZone Discussions.

## SAMPLE AND BUY

Visit the product page to see pricing options.

## **TECHNICAL SUPPORT**

Submit a technical question or find your regional support number.

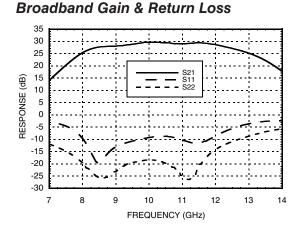
# DOCUMENT FEEDBACK

Submit feedback for this data sheet.

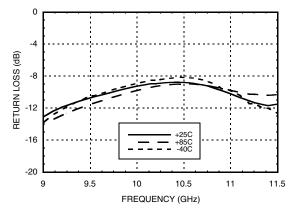


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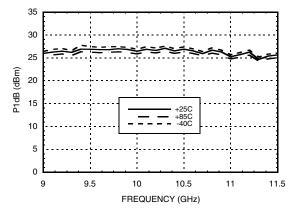
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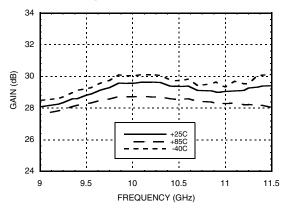
Input Return Loss vs. Temperature



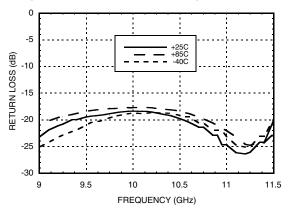
P1dB vs. Temperature



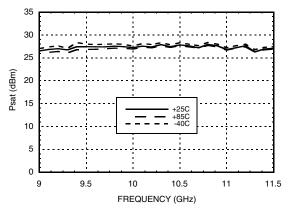
Gain vs. Temperature



### Output Return Loss vs. Temperature



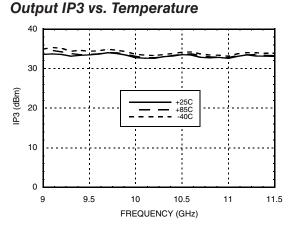
### Psat vs. Temperature



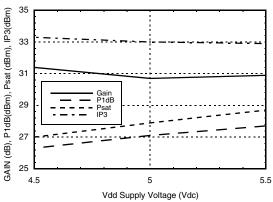


# GaAs pHEMT MEDIUM POWER AMPLIFIER, 9.5 - 11.5 GHz

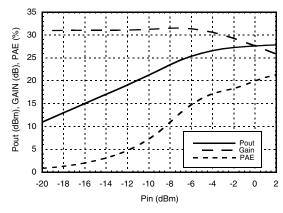
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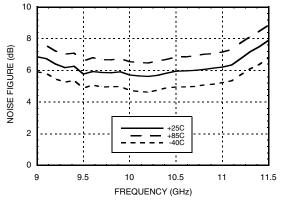
Gain, Power & Output IP3 vs. Supply Voltage @ 10.3 GHz



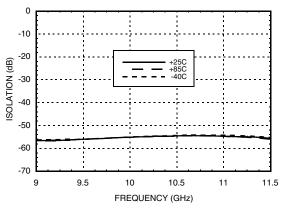
Power Compression @ 10.3 GHz



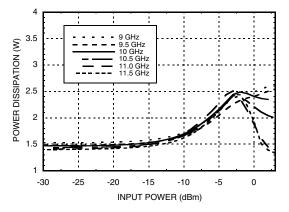




Reverse Isolation vs. Temperature



**Power Dissipation** 

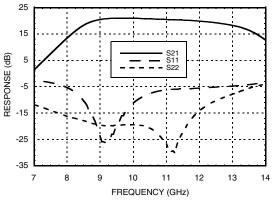




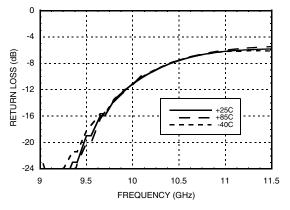
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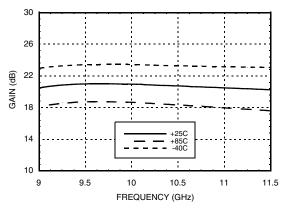
# Low Gain Mode, Broadband Gain & Return Loss



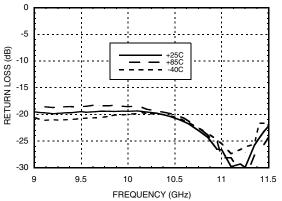
Low Gain Mode, Input Return Loss vs. Temperature



### Low Gain Mode, Gain vs. Temperature









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# Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, Vdd2, Vdd3)	7 Vdc
Gate Bias Voltage (Vgg)	-6.0 to -1.0 Vdc
RF Input Power (RFIN)(Vdd = +5Vdc)	+10 dBm
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 22.18 mW/°C above 85 °C)	2 W
Thermal Resistance (channel to ground paddle)	45 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

## Typical Supply Current vs. Vdd

Vdd (Vdc)	ldd (mA)
+4.5	300
+5.0	310
+5.5	325

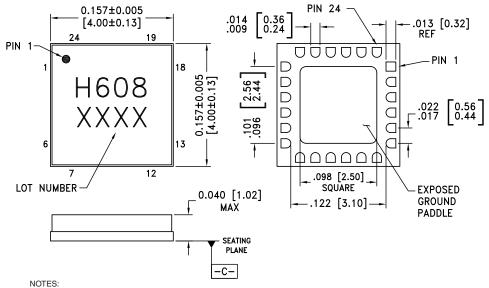
Note: Amplifier will operate over full voltage ranges shown above. Vgg adjusted to achieve Idd= 310 mA at +5V.



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

# **Outline Drawing**

BOTTOM VIEW



1. PACKAGE BODY MATERIAL: ALUMINA.

2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL

- 3. DIMENSIONS ARE IN INCHES (MILLIMETERS).
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 5. CHARACTERS TO BE HELVETICA MEDIUM, .025 HIGH, BLACK INK, OR LASER MARK LOCATED APPROX. AS SHOWN.
- 6. PACKAGE WARP SHALL NOT EXCEED 0.05MM DATUM
- 7. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

### **Package Information**

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC608LC4	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	H608 XXXX

Max peak reflow temperature of 260 °C
4-Digit lot number XXXX



# HMC608LC4

v04.0617

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# **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	Vgg	Gate control for amplifier. Adjust to achieve Id of 310 mA. Please follow "MMIC Amplifier Biasing Procedure" Application Note. External bypass capacitors of 100 pF, 1000 pF and 2.2 µF are required.	Vgg o ↓
2, 3, 7 - 12, 16 - 18, 22, 24	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
4, 6, 13, 15	GND	Package bottom has an exposed metal paddle that must also be connected to RF/DC ground.	
5	RFIN	This pin is AC coupled and matched to 50 Ohms.	
14	RFOUT	This pin is AC coupled and matched to 50 Ohms.	├ ○ RFOUT
21, 20, 19	Vdd1, Vdd2, Vdd3	Power Supply Voltage for the amplifier. External bypass capacitors of 100 pF, 1000pF, and 2.2 µF are required.	oVdd1,2,3 ↓↓ =
23	Vpd	High gain (connect to ground) / low gain mode pin control (open circuit). External bypass capacitors of 100 pF, 1000 pF and 2.2 µF are required.	Vpd 

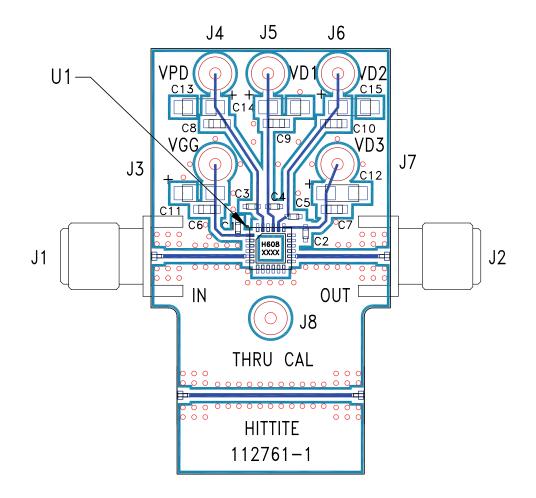


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## **Evaluation PCB**



# List of Materials for Evaluation PCB 112763 [1]

Item	Description
J1, J2	PC mount SMA connector
J3 - J8	DC Pin
C1 - C6	100 pF capacitor, 0402 pkg.
C6 - C10	1,000 pF Capacitor, 0603 pkg.
C11 - C15	2.2µF Capacitor, Tantalum
U1	HMC608LC4 Amplifier
PCB [2]	112761 Evaluation PCB

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350.

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices upon request.

AMPLIFIERS - LINEAR & POWER - SMT



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